

MC78XX/LM78XX/MC78XXA

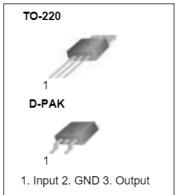
3-Terminal 1A Positive Voltage Regulator

Features

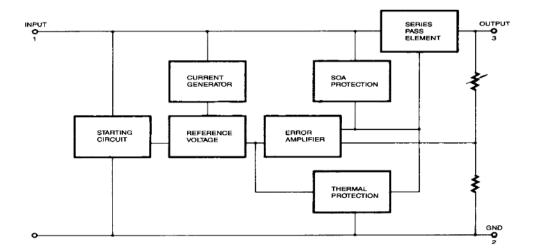
- · Output Current up to 1A
- Output Voltages of 5, 6, 8, 9, 10, 12, 15, 18, 24V
- · Thermal Overload Protection
- · Short Circuit Protection
- · Output Transistor Safe Operating Area Protection

Description

The MC78XX/LM78XX/MC78XXA series of three terminal positive regulators are available in the TO-220/D-PAK package and with several fixed output voltages, making them useful in a wide range of applications. Each type employs internal current limiting, thermal shut down and safe operating area protection, making it essentially indestructible. If adequate heat sinking is provided, they can deliver over 1A output current. Although designed primarily as fixed voltage regulators, these devices can be used with external components to obtain adjustable voltages and currents.



Internal Block Digram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for V _O = 5V to 18V) (for V _O = 24V)	VI VI	35 40	V V
Thermal Resistance Junction-Cases (TO-220)	Rejc	5	°C/W
Thermal Resistance Junction-Air (TO-220)	Reja	65	°C/W
Operating Temperature Range	TOPR	0 ~ +125	°C
Storage Temperature Range	Tstg	-65 ~ +150	°C

Electrical Characteristics (MC7805/LM7805)

(Refer to test circuit ,0°C < TJ < 125°C, IO = 500mA, VI = 10V, CI= 0.33∝F, CO= 0.1∝F, unless otherwise specified)

Parameter	Symbol	Ca	MC7	805/LM	7805	Unit	
Farameter	Syllibol		onditions	Min.	Тур.	Max.	Offic
		TJ =+25 °C		4.8	5.0	5.2	
Output Voltage	Vo	$5.0 \text{mA} \le \text{Io} \le 1.0 \text{A}, P_{\text{O}} \le 15 \text{W}$ V _I = 7V to 20V		4.75	5.0	5.25	V
Line Regulation (Note1)	Regline	T _J =+25 °C	Vo = 7V to 25V	-	4.0	100	mV
Line Regulation (Note I)	Regilile	1J=+23 C	V _I = 8V to 12V	-	1.6	50	""
			Io = 5.0mA to1.5A	-	9	100	
Load Regulation (Note1)	Regload	TJ=+25°C	IO =250mA to 750mA	-	4	50	mV
Quiescent Current	IQ	T _J =+25 °C		-	5.0	8.0	mA
Quiescent Current Change	Alo	Io = 5mA to 1.	0A	-	0.03	0.5	mA
Quiescent Current Change	ΔlQ	V _I = 7V to 25V		-	0.3	1.3	IIIA
Output Voltage Drift	ΔVο/ΔΤ	Io= 5mA		-	-0.8	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 100	OKHz, TA=+25 °C	-	42	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz Vo = 8V to 18	f = 120Hz V _O = 8V to 18V		73	-	dB
Dropout Voltage	VDrop	Io = 1A, T _J =+25 °C		-	2	-	V
Output Resistance	ro	f = 1KHz	f = 1KHz		15	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =	+25 °C	-	230	-	mA
Peak Current	IPK	T _J =+25 °C		-	2.2	-	Α

Load and line regulation are specified at constant junction temperature. Changes in V₀ due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7806)

(Refer to test circuit ,0°C < T_J < 125°C, I_O = 500mA, V_I =11V, C_I= 0.33∞F, C_O= 0.1∞F, unless otherwise specified)

Parameter	Cumbal	Co	nditions		MC7806	i	Unit
Farameter	Symbol		onditions	Min.	Тур.	Max.	Unit
		T _J =+25 °C		5.75	6.0	6.25	
Output Voltage	Vo	5.0mA ≤ IO ≤ 1.0A, PO ≤ 15W VI = 8.0V to 21V		5.7	6.0	6.3	V
Line Regulation (Note1)	Regline	T _J =+25 °C	V _I = 8V to 25V	-	5	120	mV
Line Regulation (Note I)	Regime	1J =+25 C	V _I = 9V to 13V	-	1.5	60	IIIV
Load Regulation (Note1)	Regload	T _J =+25 °C	Io =5mA to 1.5A	-	9	120	mV
Load Regulation (Note I)	Regioau	TJ =+25 °C	Io =250mA to750A	-	3	60	IIIV
Quiescent Current	IQ	T _J =+25 °C		-	5.0	8.0	mA
Ouisseent Current Change	Alo.	Io = 5mA to 1A	ı	-	-	0.5	mA
Quiescent Current Change	ΔlQ	V _I = 8V to 25V		-	-	1.3	IIIA
Output Voltage Drift	ΔV0/ΔΤ	Io = 5mA		-	-0.8	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 100K	Hz, TA =+25 °C	-	45	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz V _I = 9V to 19V			75	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ =+25 °C		-	2	-	V
Output Resistance	ro	f = 1KHz		-	19	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =+2	25 °C	-	250	-	mA
Peak Current	IPK	TJ =+25 °C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7808)

(Refer to test circuit ,0°C < T_J < 125°C, I_O = 500mA, V_I =14V, C_I= 0.33∝F, C_O= 0.1∝F, unless otherwise specified)

Parameter	Symbol	C	onditions	ı	MC780	8	Unit
raiailletei	Syllibol		onditions	Min.	Тур.	Max.	
		T _J =+25 °C		7.7	8.0	8.3	
Output Voltage	Vo	$5.0 \text{mA} \le 10 \le 1.0 \text{A}, \text{Po} \le 15 \text{W}$ VI = 10.5V to 23V		7.6	8.0	8.4	V
Line Degulation (Note1)	Doglino	T _J =+25 °C	V _I = 10.5V to 25V	-	5.0	160	mV
Line Regulation (Note1)	Regline	1J =+25 °C	V _I = 11.5V to 17V	-	2.0	80	1 mv
Load Regulation (Note1)	Doglood	T. = 125.00	Io = 5.0mA to 1.5A	-	10	160	mV
Load Regulation (Note1)	Regload	l l	Io= 250mA to 750mA	-	5.0	80	1 IIIV
Quiescent Current	IQ	T _J =+25 °C		-	5.0	8.0	mA
Quiaccent Current Change	Ala	Io = 5mA to 1.0A	A	-	0.05	0.5	mΛ
Quiescent Current Change	ΔlQ	V _I = 10.5A to 25	V	-	0.5	1.0	- mA
Output Voltage Drift	ΔV0/ΔΤ	Io = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KH	Hz, TA =+25 °C	-	52	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz, V _I = 1	1.5V to 21.5V	56	73	-	dB
Dropout Voltage	V _{Drop}	Io = 1A, T _J =+25 °C		-	2	-	V
Output Resistance	ro	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =+2	25 °C	-	230	-	mA
Peak Current	lpk	TJ =+25 °C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7809)

(Refer to test circuit ,0°C < T_J < 125°C, I_O = 500mA, V_I =15V, C_I= 0.33∝F, C_O= 0.1∝F, unless otherwise specified)

Parameter	Cumhal	Conditions		ı	MC7809	9	Unit
Farameter	Symbol		onations	Min.	Тур.	Max.	
		TJ =+25°C		8.65	9	9.35	
Output Voltage	Vo	5.0mA≤ I _O ≤1.0A, P _O ≤15W V _I = 11.5V to 24V		8.6	9	9.4	V
Line Regulation (Note1)	Doglino	TJ=+25°C	V _I = 11.5V to 25V	-	6	180	mV
Line Regulation (Note I)	Regline	1J=+25 C	V _I = 12V to 17V	-	2	90] ""
Load Regulation (Note1)	Regload	T.i=+25°C ⊢	Io = 5mA to 1.5A	-	12	180	mV
Load Regulation (Note I)	Regioau		Io = 250mA to 750mA	-	4	90] ""
Quiescent Current	IQ	TJ=+25°C		-	5.0	8.0	mA
Quiescent Current Change	Alo	Io = 5mA to 1.0A	4	-	-	0.5	mA
Quiescent Current Change	ΔlQ	V _I = 11.5V to 26	V	-	-	1.3	
Output Voltage Drift	ΔV0/ΔΤ	Io = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KH	Iz, TA =+25 °C	-	58	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz V _I = 13V to 23V			71	-	dB
Dropout Voltage	VDrop	Io = 1A, TJ=+25°C		-	2	-	V
Output Resistance	ro	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =+2	5°C	-	250	-	mA
Peak Current	IPK	TJ= +25°C			2.2	-	А

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7810)

(Refer to test circuit ,0°C< T_J < 125°C, I_O = 500mA, V_I =16V, C_I= 0.33∝F, C_O=0.1∝F, unless otherwise specified)

Parameter	Cumbal	Conditions		ı	MC7810)	Unit
Farameter	Symbol		onditions	Min.	Тур.	Max.	Onit
		TJ =+25 °C		9.6	10	10.4	
Output Voltage	Vo	5.0mA ≤ Io≤1.0A, Po ≤15W VI = 12.5V to 25V		9.5	10	10.5	V
Line Degulation (Note1)	Doglino	T 125°C	V _I = 12.5V to 25V	-	10	200	mV
Line Regulation (Note1)	Regline	TJ =+25°C	V _I = 13V to 25V	-	3	100	IIIV
Load Degulation (Note1)	Doglood	T125°C	Io = 5mA to 1.5A	-	12	200	mV
Load Regulation (Note1)	Regload	T _J =+25°C	Io = 250mA to 750mA	-	4	400	IIIV
Quiescent Current	IQ	TJ =+25°C		-	5.1	8.0	mA
Ouisseent Current Change	Alo	Io = 5mA to 1.0A	4	-	-	0.5	mA
Quiescent Current Change	ΔlQ	V _I = 12.5V to 29	V	-	-	1.0	l IIIA
Output Voltage Drift	ΔV0/ΔΤ	Io = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KH	łz, TA =+25 °C	-	58	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz V _I = 13V to 23V			71	-	dB
Dropout Voltage	VDrop	Io = 1A, TJ=+25 °C		-	2	-	V
Output Resistance	ro	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =+2	5 °C	-	250	-	mA
Peak Current	IPK	TJ =+25 °C		-	2.2	-	А

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7812)

(Refer to test circuit ,0°C < T_J < 125°C, I_O = 500mA, V_I =19V, C_I= 0.33∝F, C_O=0.1∝F, unless otherwise specified)

Parameter	Cymbol	C	onditions	I N	/IC781	2	Unit
Farameter	Symbol		onanions	Min.	Тур.	Max.	
		T _J =+25 °C		11.5	12	12.5	
Output Voltage	Vo	5.0mA ≤ IO≤1.0A VI = 14.5V to 27\		11.4	12	12.6	V
Line Degulation (Note1)	Doglino	TJ =+25 °C	V _I = 14.5V to 30V	-	10	240	mV
Line Regulation (Note1)	Regline	1J = +25 C	V _I = 16V to 22V	-	3.0	120	1110
Load Regulation (Note1)	Regload	T _J =+25 °C	Io = 5mA to 1.5A	-	11	240	mV
Load Regulation (Note I)	Regioau	I(Io = 250mA to 750mA	-	5.0	120	1110
Quiescent Current	IQ	T _J =+25 °C		-	5.1	8.0	mA
Quiocoont Current Change	Alo	Io = 5mA to 1.0A	1	-	0.1	0.5	mA
Quiescent Current Change	ΔlQ	V _I = 14.5V to 30\	/	-	0.5	1.0	MA
Output Voltage Drift	ΔV0/ΔΤ	Io = 5mA		-	-1	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 100KH	z, TA =+25 °C	-	76	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz V _I = 15V to 25V	1		71	-	dB
Dropout Voltage	VDrop	Io = 1A, TJ=+25 °C		-	2	-	V
Output Resistance	ro	f = 1KHz		-	18	-	mΩ
Short Circuit Current	Isc	VI = 35V, TA=+2	5°C	-	230	-	mA
Peak Current	IPK	TJ = +25 °C		-	2.2	-	А

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7815)

(Refer to test circuit ,0°C < T_J < 125°C, I_O = 500mA, V_I =23V, C_I= 0.33∝F, C_O=0.1∝F, unless otherwise specified)

Parameter	Cumbal	6.	I	MC7815	j	Unit	
Farameter	Symbol		onditions	Min.	Тур.	Max.	Unit
		TJ =+25 °C		14.4	15	15.6	
Output Voltage	Vo	5.0mA ≤ Io ≤ 1.0A, Po ≤ 15W VI = 17.5V to 30V		14.25	15	15.75	V
Line Degulation (Note1)	Doglino	T _J =+25 °C	V _I = 17.5V to 30V	-	11	300	mV
Line Regulation (Note1)	Regline	1J = +25 °C	V _I = 20V to 26V	-	3	150	IIIV
			Io = 5mA to 1.5A	-	12	300	
Load Regulation (Note1)	Regload	7	I _O = 250mA to 750mA	-	4	150	mV
Quiescent Current	IQ	TJ =+25 °C		-	5.2	8.0	mA
Quiescent Current Change	Alo	Io = 5mA to 1	.0A	-	-	0.5	mA
Quiescent Current Change	ΔlQ	V _I = 17.5V to 3	30V	-	-	1.0	
Output Voltage Drift	ΔVο/ΔΤ	Io = 5mA		-	-1	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 100	KHz, T _A =+25 °C	-	90	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz V _I = 18.5V to 2	f = 120Hz V _I = 18.5V to 28.5V		70	-	dB
Dropout Voltage	VDrop	I _O = 1A, T _J =+25 °C		-	2	-	V
Output Resistance	ro	f = 1KHz		-	19	-	mΩ
Short Circuit Current	Isc	VI = 35V, TA=	+25 °C	-	250	-	mA
Peak Current	Ipk	T _J =+25 °C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7818)

(Refer to test circuit ,0°C < T_J < 125°C, I_O = 500mA, V_I =27V, C_I= 0.33∝F, C_O=0.1∝F, unless otherwise specified)

Parameter	Cymbol	Conditions		N	/IC781	В	Unit
Farameter	Symbol		onations	Min.	Тур.	Max.	
		TJ =+25 °C		17.3	18	18.7	
Output Voltage	Vo	5.0mA ≤ IO ≤1.0A VI = 21V to 33V	A, Po ≤15W	17.1	18	18.9	V
Line Degulation (Note1)	Regline	T _J =+25 °C	V _I = 21V to 33V	-	15	360	mV
Line Regulation (Note1)	Regille	1J = +25 C	V _I = 24V to 30V	-	5	180	IIIV
Load Regulation (Note1)	Regload	T+25 °C	Io = 5mA to 1.5A	-	15	360	mV
Load Regulation (Note I)	Regioau		Io = 250mA to 750mA	-	5.0	180	1117
Quiescent Current	IQ	TJ =+25 °C		-	5.2	8.0	mA
Quiocoont Current Change	Alo	Io = 5mA to 1.0A	1	-	-	0.5	mA
Quiescent Current Change	ΔlQ	V _I = 21V to 33V		-	-	1	l IIIA
Output Voltage Drift	ΔV0/ΔΤ	Io = 5mA		-	-1	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 100KH	z, TA =+25 °C	-	110	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz V _I = 22V to 32V			69	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ=+25 °C		-	2	-	V
Output Resistance	ro	f = 1KHz		-	22	-	mΩ
Short Circuit Current	Isc	VI = 35V, TA=+2	5°C	-	250	-	mA
Peak Current	IPK	TJ =+25 °C		-	2.2	-	А

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7824)

(Refer to test circuit ,0°C < T_J < 125°C, I_O = 500mA, V_I =33V, C_I= 0.33∝F, C_O=0.1∝F, unless otherwise specified)

Parameter	Cumbal	C	onditions	N	/IC782	4	Unit
Farameter	Symbol		onations	Min.	Тур.	Max.	Onit
		T _J =+25 °C		23	24	25	
Output Voltage	Vo	5.0mA ≤ I _O ≤ 1.0A, P _O ≤ 15W V _I = 27V to 38V		22.8	24	25.25	V
Line Regulation (Note1)	Regline	T _J =+25 °C	V _I = 27V to 38V	-	17	480	mV
Line Regulation (Note I)	Regille	1J = +25 C	V _I = 30V to 36V	-	6	240] '''V
Load Population (Note1)	Regload	TJ =+25 °C	Io = 5mA to 1.5A	-	15	480	mV
Load Regulation (Note1)	Regioau	1J = +25 C	Io = 250mA to 750mA	-	5.0	240	1 111
Quiescent Current	IQ	TJ =+25 °C		-	5.2	8.0	mA
Quiescent Current Change	Alo	Io = 5mA to 1.0A	1	-	0.1	0.5	mA
Quiescent Current Change	ΔlQ	V _I = 27V to 38V		-	0.5	1	I IIIA
Output Voltage Drift	ΔV0/ΔΤ	Io = 5mA		-	-1.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KH	z, TA =+25 °C	-	60	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz V _I = 28V to 38V	I		67	-	dB
Dropout Voltage	VDrop	Io = 1A, T _J =+25 °C		-	2	-	V
Output Resistance	ro	f = 1KHz		-	28	-	mΩ
Short Circuit Current	Isc	VI = 35V, TA=+2	5 °C	-	230	-	mA
Peak Current	IPK	TJ =+25 °C		-	2.2	-	А

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7805A)

(Refer to the test circuits. 0° C < T_J < 125° C, I_{0} =1A, V $_{I}$ = 10V, C $_{I}$ =0.33 $_{\odot}$ F, C $_{O}$ =0.1 $_{\odot}$ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		TJ =+25 °C		4.9	5	5.1	
Output Voltage	Vo	I _O = 5mA to 1 V _I = 7.5V to 2		4.8	5	5.2	V
		V _I = 7.5V to 2 I _O = 500mA	5V	-	5	50	
Line Regulation (Note1)	Regline	V _I = 8V to 12	V	-	3	50	mV
		T _J =+25 °C	V _I = 7.3V to 20V	-	5	50	1
		1J =+25 °C	V _I = 8V to 12V	-	1.5	25	1
Load Regulation (Note1)	5	T _J =+25 °C Io = 5mA to 1	.5A	-	9	100	.,
	Regload	Io = 5mA to 1	Io = 5mA to 1A		9	100	mV
		Io = 250mA to	o 750mA	-	4	50	1
Quiescent Current	IQ	TJ =+25 °C		-	5.0	6	mA
		I _O = 5mA to 1A		-	-	0.5	
Quiescent Current Change	ΔlQ	V _I = 8 V to 25	V _I = 8 V to 25V, I _O = 500mA		-	0.8	mA
Chango		VI = 7.5V to 2	VI = 7.5V to 20V, TJ =+25 °C		-	0.8	
Output Voltage Drift	ΔV/ΔΤ	Io = 5mA		-	-0.8	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 10 T _A =+25 °C	00KHz	-	10	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz, I _O V _I = 8V to 18 ^o	-	68	-	dB	
Dropout Voltage	VDrop	Io = 1A, T _J =	+25 °C	-	2	-	V
Output Resistance	ro	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =	÷+25 °C	-	250	-	mA
Peak Current	IPK	T _J = +25 °C		-	2.2	-	А

Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7806A)

(Refer to the test circuits. 0°C < T_J < 125°C, I_O =1A, V _I =11V, C _I=0.33∝F, C _O=0.1∝F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T _J =+25 °C		5.58	6	6.12	
Output Voltage	Vo	I _O = 5mA to 1 V _I = 8.6V to 2		5.76	6	6.24	V
		V _I = 8.6V to 25 I _O = 500mA	5V	-	5	60	
Line Regulation (Note1)	Regline	V _I = 9V to 13V	1	-	3	60	mV
		T _J =+25 °C	V _I = 8.3V to 21V	-	5	60	
		1J =+25 °C	V _I = 9V to 13V	-	1.5	30	
Load Regulation (Note1)		T _J =+25 °C Io = 5mA to 1	.5A	-	9	100	.,
	Regload	Io = 5mA to 1	A	-	4	100	mV
		Io = 250mA to	o 750mA	-	5.0	50	
Quiescent Current	IQ	TJ =+25 °C		-	4.3	6	mA
		Io = 5mA to 1A		-	-	0.5	
Quiescent Current Change	ΔlQ	V _I = 9V to 25V, I _O = 500mA		-	-	0.8	mA
		VI= 8.5V to 21V, TJ =+25 °C		-	-	0.8	
Output Voltage Drift	ΔV/ΔΤ	Io = 5mA		-	-0.8	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 10 T _A =+25 °C	00KHz	-	10	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 500mA V _I = 9V to 19V		-	65	-	dB
Dropout Voltage	VDrop	I _O = 1A, T _J =+25 °C		-	2	-	V
Output Resistance	rO	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =	:+25 °C	-	250	-	mA
Peak Current	IPK	T _J =+25 °C		-	2.2	-	Α

Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7808A)

(Refer to the test circuits. 0°C < TJ < 125°C, I₀ =1A, V I = 14V, C I=0.33∝F, C O=0.1∝F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T _J =+25 °C		7.84	8	8.16	
Output Voltage	Vo	Io = 5mA to 1 V _I = 10.6V to		7.7	8	8.3	V
		V _I = 10.6V to 2 IO = 500mA	25V	-	6	80	
Line Regulation (Note1)	Regline	V _I = 11V to 17	7 V	-	3	80	mV
		T.j =+25 °C	V _I = 10.4V to 23V	-	6	80	1
		1J =+25 °C	Vi= 11V to 17V	-	2	40]
Load Regulation (Note1)		T _J =+25 °C I _O = 5mA to 1	T _J =+25 °C I _O = 5mA to 1.5A		12	100	mV
Louis rogalisation (receive)	Regload	Io = 5mA to 1A		-	12	100	
		I _O = 250mA to 750mA		-	5	50	
Quiescent Current	IQ	T _J =+25 °C		-	5.0	6	mA
		Io = 5mA to 1A		-	-	0.5	
Quiescent Current Change	ΔlQ	V _I = 11V to 25V, I _O = 500mA		-	-	0.8	mA
		V _I = 10.6V to 23V, T _J =+25 °C		-	-	0.8	1
Output Voltage Drift	ΔV/ΔΤ	Io = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KHz TA =+25 °C		-	10	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 500mA V _I = 11.5V to 21.5V		-	62	-	dB
Dropout Voltage	VDrop	I _O = 1A, T _J =+25 °C		-	2	-	V
Output Resistance	ro	f = 1KHz		-	18	-	mΩ
Short Circuit Current	Isc	VI= 35V, TA =+25 °C		-	250	-	mA
Peak Current	IPK	T _J =+25 °C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7809A)

(Refer to the test circuits. 0°C < T_J < 125°C, I_O =1A, V_J = 15V, C_J=0.33∞F, C_O=0.1∞F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T _J =+25°C		8.82	9.0	9.18	
Output Voltage	Vo	I _O = 5mA to 1A, P _O ≤15W V _I = 11.2V to 24V		8.65	9.0	9.35	V
		V _I = 11.7V to 2 I _O = 500mA	25V	-	6	90	
Line Regulation (Note1)	Regline	V _I = 12.5V to '	19V	-	4	45	mV
		T _J =+25°C	V _I = 11.5V to 24V	-	6	90	
		1J =+25 C	V _I = 12.5V to 19V	-	2	45	
Load Regulation (Note1)	TJ =		.0A	-	12	100	mV
	Regload	I _O = 5mA to 1.0A		-	12	100	
		I _O = 250mA to 750mA		-	5	50	
Quiescent Current	IQ	TJ =+25 °C		-	5.0	6.0	mA
	ΔlQ	V _I = 11.7V to 25V, T _J =+25 °C		-	-	0.8	
Quiescent Current Change		V _I = 12V to 25V, I _O = 500mA		-	-	0.8	mA
		Io = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift	ΔV/ΔΤ	Io = 5mA		-	-1.0	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 100KHz T _A =+25 °C		-	10	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 500mA V _I = 12V to 22V		-	62	-	dB
Dropout Voltage	VDrop	I _O = 1A, T _J =+25 °C		-	2.0	-	V
Output Resistance	ro	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =	:+25 °C	-	250	-	mA
Peak Current	IPK	TJ=+25°C		-	2.2	-	А

^{1.} Load and line regulation are specified at constant, junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7810A)

(Refer to the test circuits. 0° C < T_J < 125° C, I_{0} =1A, V $_{I}$ = 16V, C $_{I}$ =0.33 $_{\odot}$ F, C $_{O}$ =0.1 $_{\odot}$ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		TJ =+25°C		9.8	10	10.2	
Output Voltage	Vo	I _O = 5mA to 1A, P _O ≤ 15W V _I =12.8V to 25V		9.6	10	10.4	V
		V _I = 12.8V to I _O = 500mA	26V	-	8	100	
Line Regulation (Note1)	Regline	V _I = 13V to 20	V	-	4	50	mV
		T _J =+25 °C	VI= 12.5V to 25V	-	8	100	
		1J=+25 C	V _I = 13V to 20V	-	3	50	
Load Regulation (Note1)		T _J =+25 °C I _O = 5mA to 1.5A		-	12	100	m\/
20dd Hogaldion (Hotol)	Regload	I _O = 5mA to 1.0A		-	12	100	
		Io = 250mA to 750mA		-	5	50	
Quiescent Current	IQ	TJ =+25 °C		-	5.0	6.0	mA
		V _I = 13V to 2	6V, TJ=+25 °C	-	-	0.5	.5
Quiescent Current Change	ΔlQ	V _I = 12.8V to 25V, I _O = 500mA		-	-	0.8	mA
		Io = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift	ΔV/ΔΤ	Io = 5mA		-	-1.0	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 100KHz T _A =+25 °C		-	10	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 500mA V _I = 14V to 24V		-	62	-	dB
Dropout Voltage	VDrop	I _O = 1A, T _J =+25°C		-	2.0	-	V
Output Resistance	ro	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A :	=+25 °C	-	250	-	mA
Peak Current	IPK	TJ=+25 °C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7812A)

(Refer to the test circuits. 0° C < T_J < 125° C, I_{0} =1A, V $_{I}$ = 19V, C $_{I}$ =0.33 $_{\odot}$ F, C $_{O}$ =0.1 $_{\odot}$ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T _J =+25 °C		11.75	12	12.25	
Output Voltage	Vo		I _O = 5mA to 1A, P _O ≤15W V _I = 14.8V to 27V		12	12.5	V
		V _I = 14.8V to I _O = 500mA	30V	-	10	120	
Line Regulation (Note1)	Regline	V _I = 16V to 22	2V	-	4	120	mV
		T _J =+25 °C	V _I = 14.5V to 27V	-	10	120	
		1J = +25 C	V _I = 16V to 22V	-	3	60	
Load Regulation (Note1)		T _J =+25 °C IO = 5mA to 1.5A		-	12	100	mV
	Regload	Io = 5mA to 1.0A		-	12	100	
		Io = 250mA t	to 750mA	-	5	50	
Quiescent Current	IQ	TJ =+25°C		-	5.1	6.0	mA
		V _I = 15V to 3	0V, TJ=+25 °C	-		0.8	
Quiescent Current Change	ΔlQ	V _I = 14V to 27V, I _O = 500mA		-		0.8	mA
		Io = 5mA to 1.0A		-		0.5	
Output Voltage Drift	ΔV/ΔΤ	Io = 5mA		-	-1.0	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KHz T _A =+25°C		-	10	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 500mA V _I = 14V to 24V		-	60	-	dB
Dropout Voltage	V _{Drop}	I _O = 1A, T _J =+25°C		-	2.0	-	V
Output Resistance	ro	f = 1KHz		-	18	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A :	=+25 °C	-	250	-	mA
Peak Current	IPK	T _J =+25 °C		-	2.2	-	Α

Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7815A)

(Refer to the test circuits. 0°C < T_J < 125°C, I_O =1A, V_I =23V, C_I=0.33∝F, C_O=0.1∝F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
			T _J =+25 °C		15	15.3	
Output Voltage	Vo	Io = 5mA to ' V _I = 17.7V to		14.4	15	15.6	V
		V _I = 17.9V to I _O = 500mA	30V	-	10	150	
Line Regulation (Note1)	Regline	V _I = 20V to 26	V	-	5	150	mV
		T _J =+25°C	VI= 17.5V to 30V	-	11	150	
		1J=+25 C	V _I = 20V to 26V	-	3	75	
Load Regulation (Note1)	T _J =+25		1.5A	-	12	100	.,
	Regload	I _O = 5mA to 1.0A		-	12	100	mV
		I _O = 250mA to 750mA		-	5	50	
Quiescent Current	IQ	TJ =+25 °C		-	5.2	6.0	mA
		V _I = 17.5V to	V _I = 17.5V to 30V, T _J =+25 °C		-	0.8	
Quiescent Current Change	ΔlQ	V _I = 17.5V to	30V, Io = 500mA	-	-	0.8	mA
		IO = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift	ΔV/ΔΤ	Io = 5mA		-	-1.0	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KHz T _A =+25 °C		-	10	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 500mA V _I = 18.5V to 28.5V		-	58	-	dB
Dropout Voltage	VDrop	I _O = 1A, T _J =+25 °C		-	2.0	-	V
Output Resistance	ro	f = 1KHz		-	19	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =+25 °C		-	250	-	mA
Peak Current	IPK	T _J =+25°C		-	2.2	-	А

Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7818A)

(Refer to the test circuits. 0°C < T_J < 125°C, I_O =1A, V_J = 27V, C_J=0.33∞F, C_O=0.1∞F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T _J =+25 °C		17.64	18	18.36	
Output Voltage	Vo		I _O = 5mA to 1A, P _O ≤15W V _I = 21V to 33V		18	18.7	V
		V _I = 21V to 33 I _O = 500mA	3V	-	15	180	
Line Regulation (Note1)	Regline	V _I = 21V to 33	3V	-	5	180	mV
		T _J =+25 °C	VI= 20.6V to 33V	-	15	180	
		1J =+25 C	V _I = 24V to 30V	-	5	90	
Load Regulation (Note1)	5	T _J =+25°C I _O = 5mA to 1.5A		-	15	100	m\/
20dd Hogaldion (Hotol)	Regload	Io = 5mA to 1.0A		-	15	100	
		Io = 250mA to 750mA		-	7	50	
Quiescent Current	IQ	TJ =+25 °C		-	5.2	6.0	mA
		V _I = 21V to 3	3V, TJ=+25 °C	-	- 0	0.8	
Quiescent Current Change	ΔlQ	V _I = 21V to 33V, I _O = 500mA		-	-	0.8	mA
		Io = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift	ΔV/ΔΤ	Io = 5mA		-	-1.0	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 100KHz T _A =+25°C		-	10	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 500mA V _I = 22V to 32V		-	57	-	dB
Dropout Voltage	V _{Drop}	I _O = 1A, T _J =+25°C		-	2.0	-	V
Output Resistance	ro	f = 1KHz		-	19	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =	=+25°C	-	250	-	mA
Peak Current	IPK	T _J =+25 °C		-	2.2	-	Α

Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7824A)

(Refer to the test circuits. 0°C < T_J < 125°C, I_O =1A, V_J = 33V, C_J=0.33∞F, C_O=0.1∞F, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		TJ =+25 °C	$T_J = +25 ^{\circ}C$ $I_O = 5mA \text{ to } 1A, P_O \le 15W$ $V_I = 27.3V \text{ to } 38V$		24	24.5	
Output Voltage	Vo				24	25	V
		V _I = 27V to 38 I _O = 500mA	3V	-	18	240	
Line Regulation (Note1)	Regline	V _I = 21V to 33	3V	-	6	240	mV
		T _J =+25 °C	VI= 26.7V to 38V	-	18	240	
		1J=+25 C	V _I = 30V to 36V	-	6	120	
Load Regulation (Note1)		T _J =+25 °C I _O = 5mA to 1.5A		-	15	100	100 100 mV
20dd Hogaldion (Hotol)	Regload	Io = 5mA to 1.0A		-	15	100	
		I _O = 250mA to 750mA		-	7	50	
Quiescent Current	IQ	TJ =+25 °C		-	5.2	6.0	mA
		V _I = 27.3V to 38V, T _J =+25 °C		-	-	0.8	mA
Quiescent Current Change	ΔlQ	V _I = 27.3V to	V _I = 27.3V to 38V, I _O = 500mA		-	0.8	
		Io = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift	ΔV/ΔΤ	Io = 5mA		-	-1.5	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 100KHz T _A = 25 °C		-	10	-	∞V/Vo
Ripple Rejection	RR	f = 120Hz, IO = 500mA VI = 28V to 38V		-	54	-	dB
Dropout Voltage	VDrop	I _O = 1A, T _J =+25 °C		-	2.0	-	V
Output Resistance	ro	f = 1KHz		-	20	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A :	=+25 °C	-	250	-	mA
Peak Current	IPK	T _J =+25 °C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Change in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Typical Perfomance Characteristics

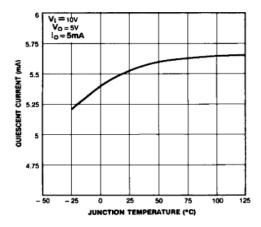


Figure 1. Quiescent Current

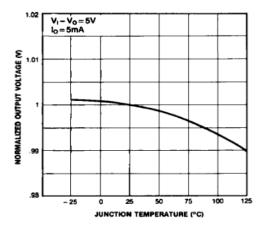


Figure 3. Output Voltage

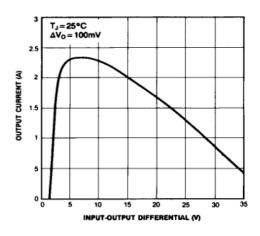


Figure 2. Peak Output Current

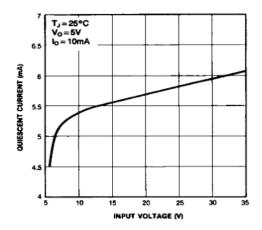


Figure 4. Quiescent Current

Typical Applications

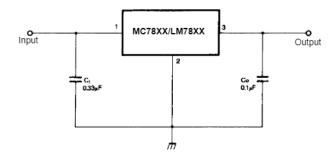


Figure 5. DC Parameters

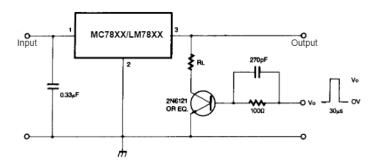


Figure 6. Load Regulation

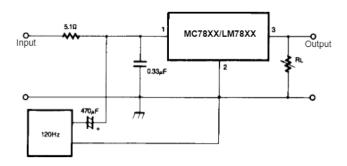


Figure 7. Ripple Rejection

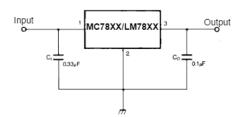


Figure 8. Fixed Output Regulator

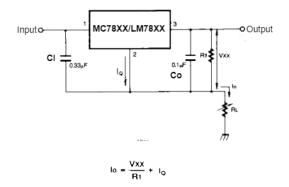
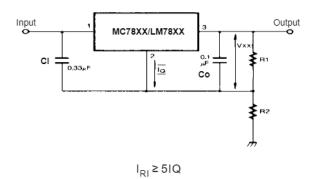
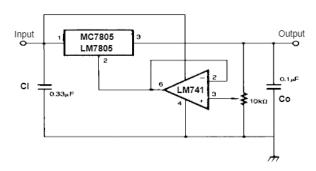


Figure 9. Constant Current Regulator

- (1) To specify an output voltage. substitute voltage value for "XX." A common ground is required between the input and the Output voltage. The input voltage must remain typically 2.0V above the output voltage even during the low point on the input ripple voltage.
- (2) C_I is required if regulator is located an appreciable distance from power Supply filter.
- (3) Co improves stability and transient response.



 $\label{eq:VQ} V_O = V_{XX}(1+R_2/R_1) + I_QR_2$ Figure 10. Circuit for Increasing Output Voltage



 $I_{RI} \ge 5 \ I_{Q}$ $V_{O} = V_{XX}(1+R_{2}/R_{1}) + I_{Q}R_{2}$ Figure 11. Adjustable Output Regulator (7 to 30V)

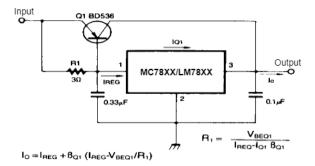


Figure 12. High Current Voltage Regulator

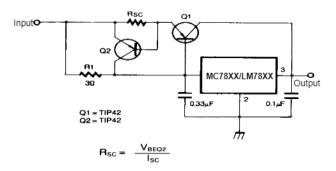


Figure 13. High Output Current with Short Circuit Protection

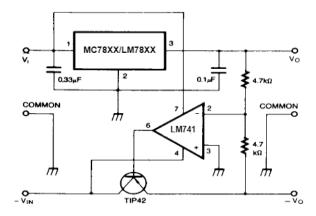


Figure 14. Tracking Voltage Regulator

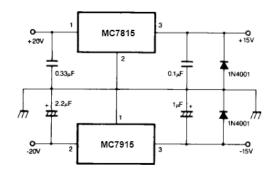


Figure 15. Split Power Supply (±15V-1A)

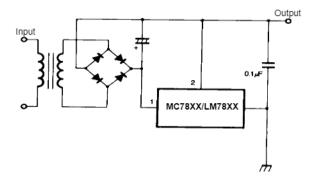


Figure 16. Negative Output Voltage Circuit

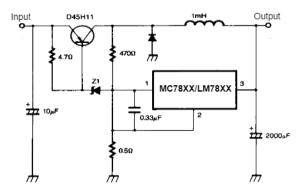
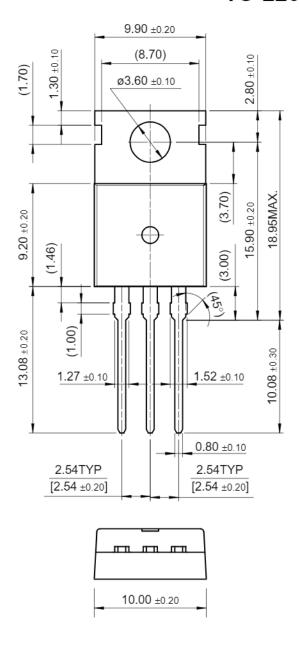


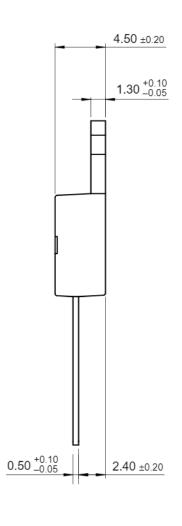
Figure 17. Switching Regulator

Mechanical Dimensions

Package

TO-220





Mechancal Dimensions (Continued)

Package

D-PAK 6.60 ±0.20 0.70 ±0.20 5.34 ± 0.30 2.30 ±0.10 (0.50)(0.50)(4.34)0.50 ±0.10 0.60 ±0.20 6.10 ±0.20 0.91 ±0.10 9.50 ±0.30 2.70 ±0.20 MIN0.55 0.80 ±0.20 0.89 ±0.10 MAX0.96 0.76 ±0.10 0.50 ±0.10 1.02 ±0.20 2.30TYP 2.30TYP [2.30±0.20] [2.30±0.20] 2.30 ±0.20 6.60 ±0.20 (5.34)(5.04)(0.90)(1.00)(1.50)(3.05) 6.10 ± 0.20 (2XR|0.25) 9.50 ±0.30 2.70 ± 0.20

0.76 ±0.10

Ordering Information

Product Number	Output Voltage Tolerance	Package	Operating Temperature
LM7805CT	±4%	TO-220	0 ~ + 125°C

Product Number	Output Voltage Tolerance	Package	Operating Temperature
MC7805CT			
MC7806CT			
MC7808CT			
MC7809CT			
MC7810CT		TO-220	
MC7812CT			
MC7815CT			
MC7818CT	±4%		
MC7824CT			
MC7805CDT			
MC7806CDT		D-PAK	
MC7808CDT			0 ~ + 125°C
MC7809CDT			0 - + 125 0
MC7810CDT			
MC7812CDT			
MC7805ACT			
MC7806ACT			
MC7808ACT			
MC7809ACT			
MC7810ACT	±2%	TO-220	
MC7812ACT			
MC7815ACT			
MC7818ACT			
MC7824ACT			

DISCLAIMER

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